

20V P-Channel

## **MOSFET**

**Product Summary** 

V(BR)DSS	R <sub>DS(on)MAX</sub>	l <sub>D</sub>
-20V	110mΩ@-4.5V	-2.3A
-20V	140mΩ@-2.5V	-2.5A

#### **Feature**

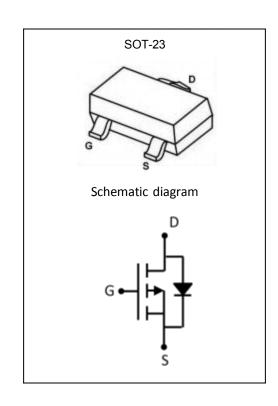
- TrenchFET Power MOSFET
- Excellent R<sub>DS(on)</sub> and Low Gate Charge

## **Application**

- DC/DC Converter
- Load Switch for Portable Devices
- Battery Switch

### **MARKING:**





## ABSOLUTE MAXIMUM RATINGS (Ta=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DS</sub>	-20	V
Gate-Source Voltage	Vgs	±8	V
Continuous Drain Current	ID	-2.3	A
Pulsed Drain Current (t=300µs)	I <sub>DM</sub>	-10	A
Power Dissipation	P <sub>D</sub>	0.35	W
Thermal Resistance from Junction to Ambient	Reja	357	°C/W
Junction Temperature	TJ	150	$^{\circ}$
Storage Temperature	T <sub>STG</sub>	-55~ +150	℃



# MOSFET ELECTRICAL CHARACTERISTICS(Ta=25℃ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Static Characteristics			•			
Drain-source breakdown voltage	V(BR)DSS	V <sub>GS</sub> = 0V, I <sub>D</sub> =-250µA	-20			V
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V,V <sub>GS</sub> = 0V			-1	μA
Gate-body leakage current	Igss	V <sub>GS</sub> =±8V, V <sub>DS</sub> = 0V			±100	nΑ
Gate threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA	-0.4	-0.7	-1	V
Dunin an una an unaistance	-	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-3A		70	110	
Drain-source on-resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-2A		110	140	mΩ
Forward tranconductance <sup>a</sup>	<b>g</b> FS	V <sub>DS</sub> =-5V, I <sub>D</sub> =-2A	5			S
Dynamic characteristics <sup>b</sup>						
Input Capacitance	Ciss			405		
Output Capacitance	Coss	V <sub>DS</sub> =-10V,V <sub>GS</sub> =0V,f =1MHz		75		pF
Reverse Transfer Capacitance	Crss			55		
Gate resistance	Rg	f=1MHz		6		Ω
Total Gate Charge	Qg			3.3	12	
Gate-Source Charge	Qgs	V <sub>DS</sub> =-10V,V <sub>GS</sub> =-2.5V,I <sub>D</sub> =-3A		0.7		nC
Gate-Drain Charge	Qgd			1.3		
Turn-on delay time	t <sub>d(on)</sub>			11		
Turn-on rise time	tr	V <sub>DD</sub> =-10V,V <sub>GEN</sub> =-4.5V,I <sub>D</sub> =-1A		35		20
Turn-off delay time	t <sub>d(off)</sub>	$R_L=10\Omega, R_{GEN}=1\Omega$		30		ns
Turn-off fall time	t <sub>f</sub>			10		
Source-Drain Diode characteristics	<b>S</b>					
Diode forward current	Is	Tc=25℃			-2.3	Α
Diode pulsed forward current <sup>a</sup>	Ism				-10	Α
Diode Forward voltage	V <sub>DS</sub>	V <sub>G</sub> S =0V, I <sub>S</sub> =-1.3A			-1.2	V

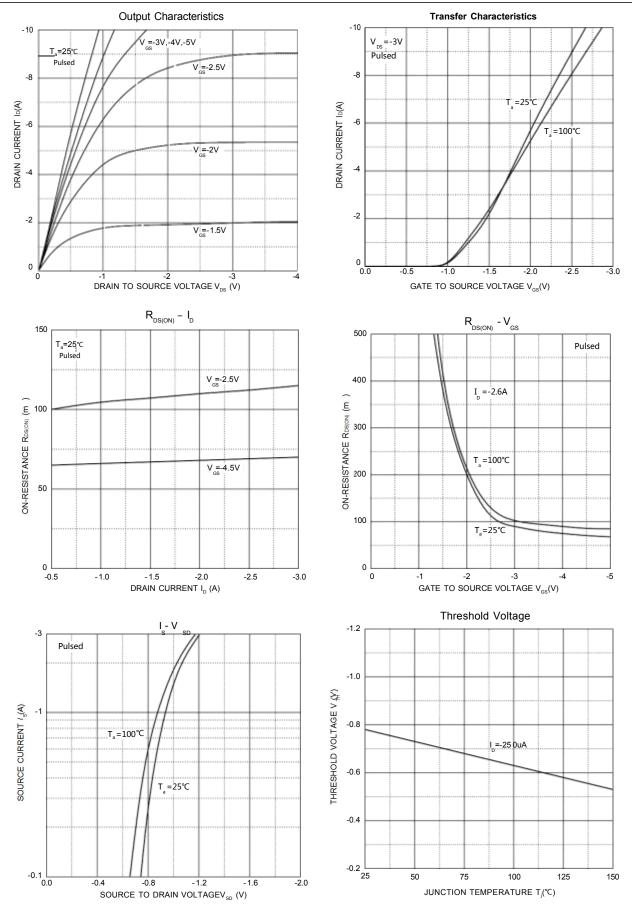
Notes:

a.Pulse Test : Pulse Width < 300µs, Duty Cycle ≤2%.

b.Guaranteed by design, not subject to production testing.

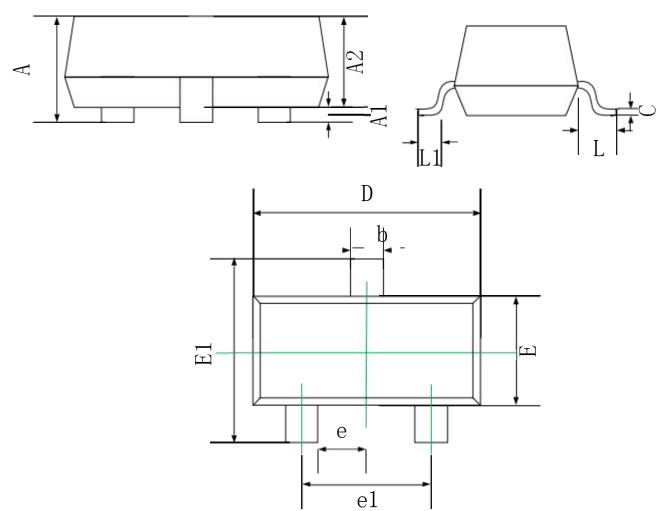


### Typical Electrical and Thermal Characteristics





# **SOT-23 Package Information**



Comple of	Dimensions In Millimeters				
Symbol	Min.	Max.			
Α	0.90	1.15			
A1	0.00	0.10			
A2	0.90	1.05			
b	0.30	0.50			
С	0.08	0.15			
D	2.80	3.00			
E	1.20	1.40			
E1	2.25	2.55			
е	0.95 REF.				
e1	1.80	2.00			
L	0.55	REF.			
L1	0.30	0.50			

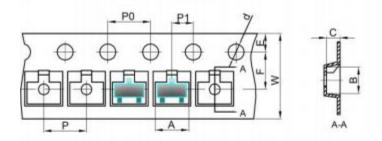
REV: AO AUG. 2021



**SOT-23 Tape and Reel** 

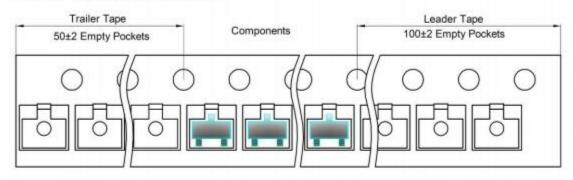
# SOT-23 Tape and reel

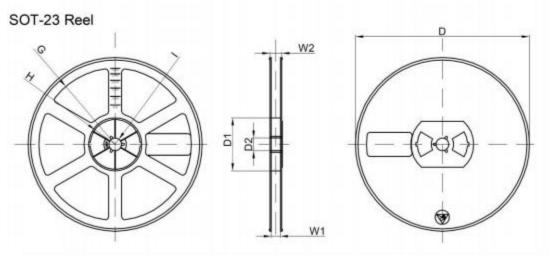
# SOT-23 Embossed Carrier Tape



Dimensions are in millimeter										
Pkg type	A	В	С	d	E	F	P0	Р	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

# SOT-23 Tape Leader and Trailer





Dimensions are in millimeter									
Reel Option	D	D1	D2	G	н	E.	W1	W2	
7°Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30	

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	



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